



**THE DATASHEET OF
MC74AC00DR2**



Quad 2-Input NAND Gate

High-Performance Silicon-Gate CMOS

MC74AC00, MC74ACT00

Features

- Output Drive Capability: ± 24 mA
- Operating Voltage Range: 2 to 6 V AC00; 4.5 to 5.5 ACT00
- Low Input Current: 1.0 μ A
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance With the JEDEC Standard No. 7A Requirements
- Chip Complexity: 32 FETs
- These are Pb-Free Devices

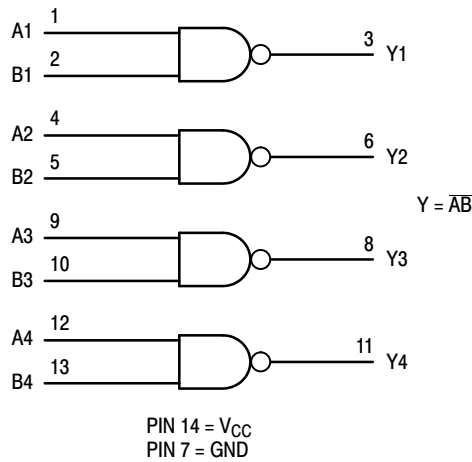


Figure 1. Logic Diagram

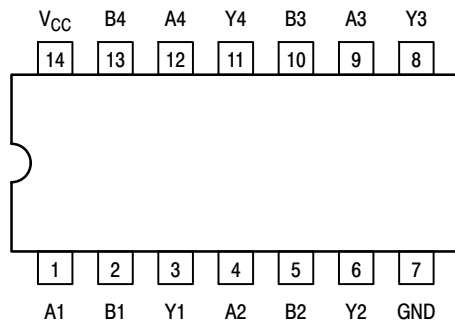
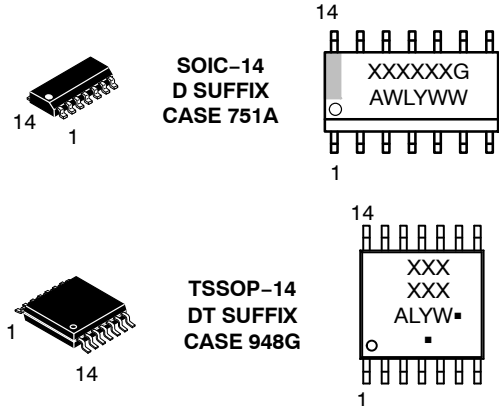


Figure 2. Pinout: 14-Lead Packages (Top View)

MARKING DIAGRAMS



SOIC-14
D SUFFIX
CASE 751A

TSSOP-14
DT SUFFIX
CASE 948G

XXXXXX = Specific Device Code
A = Assembly Location
WL or L = Wafer Lot
Y = Year
WW or W = Work Week
G or \blacksquare = Pb-Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MC74AC00, MC74ACT00

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V
V _I	DC Input Voltage	-0.5 ≤ V _I ≤ V _{CC} + 0.5	V
V _O	DC Output Voltage (Note 1)	-0.5 ≤ V _O ≤ V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	±20	mA
I _{OK}	DC Output Diode Current	±50	mA
I _O	DC Output Sink/Source Current	±50	mA
I _{CC}	DC Supply Current per Output Pin	±50	mA
I _{GND}	DC Ground Current per Output Pin	±50	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
T _L	Lead temperature, 1 mm from Case for 10 Seconds	260	°C
T _J	Junction temperature under Bias	+150	°C
θ _{JA}	Thermal Resistance (Note 2)	SOIC TSSOP 116 150	°C/W
P _D	Power Dissipation in Still Air at 25°C	SOIC TSSOP 1077 833	mW
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating	Oxygen Index: 30% – 35% UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Charged Device Model (Note 4) > 2000 > 1000	V
I _{Latch-Up}	Latch-Up Performance	Above V _{CC} and Below GND at 85°C (Note 5)	±100 mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.
2. The package thermal impedance is calculated in accordance with JESD51-7.
3. Tested to EIA/JESD22-A114-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V _{CC}	Supply Voltage	MC74AC00 2.0 MC74ACT00 4.5	5.0 5.0	6.0 5.5	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Ref. to GND)	0	-	V _{CC}	V
t _r , t _f	Input Rise and Fall Time (Note 6) MC74AC00	V _{CC} @ 3.0 V - V _{CC} @ 4.5 V - V _{CC} @ 5.5 V -	150 40 25	- - -	ns/V
t _r , t _f	Input Rise and Fall Time (Note 7) MC74ACT00	V _{CC} @ 4.5 V - V _{CC} @ 5.5 V -	10 8.0	- -	ns/V
T _J	Junction Temperature	-	-	150	°C
T _A	Operating Ambient Temperature Range	-55	25	125	°C
I _{OH}	Output Current – High	-	-	-24	mA
I _{OL}	Output Current – Low	-	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. V_{in} from 30% to 70% V_{CC}.
7. V_{in} from 0.8 V to 2.0 V.

MC74AC00, MC74ACT00

DC CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	MC74AC00						Unit	Conditions
			T _A = +25°C		T _A = -40°C to +85°C		T _A = -55°C to +125°C			
			Typ		Guaranteed Limits					
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1		2.1		V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
		4.5	2.25	3.15	3.15		3.15			
		5.5	2.75	3.85	3.85		3.85			
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9		0.9		V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
		4.5	2.25	1.35	1.35		1.35			
		5.5	2.75	1.65	1.65		1.65			
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9		2.9		V	I _{OUT} = -50 μA
		4.5	4.49	4.4	4.4		4.4			
		5.5	5.49	5.4	5.4		5.4			
		3.0	-	2.56	2.46		2.4		V	*V _{IN} = V _{IL} or V _{IH} -12 mA I _{OH} -24 mA -24 mA
		4.5	-	3.86	3.76		3.7			
		5.5	-	4.86	4.76		4.7			
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1		0.1		V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1		0.1			
		5.5	0.001	0.1	0.1		0.1			
		3.0	-	0.36	0.44		0.5		V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
		4.5	-	0.36	0.44		0.5			
		5.5	-	0.36	0.44		0.5			
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0		±1.0		μA	V _I = V _{CC} , GND
I _{OLD}	†Minimum Dynamic Output Current	5.5	-	-	75		50		mA	V _{OLD} = 1.65 V Max
I _{OHD}		5.5	-	-	-75		-50		mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	4.0	40		40		μA	V _{IN} = V _{CC} or GND

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

AC CHARACTERISTICS (t_r = t_f = 3.0 nS; C_L = 50 pF; see Figures 3 and 4 for Waveforms)

Symbol	Parameter	V _{CC} * (V)	MC74AC00								Unit
			T _A = +25°C			T _A = -40°C to +85°C		T _A = -55°C to +125°C			
			Min	Typ	Max	Min	Max	Min	Max		
t _{PLH}	Propagation Delay	3.3	2.0	7.0	9.5	2.0	10.0	1.0	11.0	ns	
		5.0	1.5	6.0	8.0	1.5	8.5	1.0	8.5		
t _{PHL}	Propagation Delay	3.3	1.5	5.5	8.0	1.0	8.5	1.0	9.0	ns	
		5.0	1.5	4.5	6.5	1.0	7.0	1.0	7.0		

*Voltage Range 3.3 V is 3.3 V ± 0.3 V.

Voltage Range 5.0 V is 5.0 V ± 0.5 V.

MC74AC00, MC74ACT00

DC CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	MC74ACT00				Unit	Conditions
			T _A = +25°C		T _A = -40°C to +85°C	T _A = -55°C to +125°C		
			Typ	Guaranteed Limits				
V _{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	2.0	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
		5.5	1.5	2.0	2.0	2.0		
V _{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8	0.8	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
		5.5	1.5	0.8	0.8	0.8		
V _{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	4.4	V	I _{OUT} = -50 μA
		5.5	5.49	5.4	5.4	5.4		
		4.5	-	3.86	3.76	3.7	V	*V _{IN} = V _{IL} or V _{IH} I _{OH} = -24 mA -24 mA
		5.5	-	4.86	4.76	4.7		
V _{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	0.1	V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1	0.1		
		4.5	-	0.36	0.44	0.5	V	*V _{IN} = V _{IL} or V _{IH} I _{OL} = 24 mA 24 mA
		5.5	-	0.36	0.44	0.5		
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	±1.0	μA	V _I = V _{CC} , GND
ΔI _{CC} T	Additional Max. I _{CC} /Input	5.5	0.6	-	1.5	1.6	mA	V _I = V _{CC} - 2.1 V
I _{OLD}	†Minimum Dynamic Output Current	5.5	-	-	75	50	mA	V _{OLD} = 1.65 V Max
I _{OHD}		5.5	-	-	-75	-50	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	4.0	40	40	μA	V _{IN} = V _{CC} or GND

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (t_r = t_f = 3.0 nS; C_L = 50 pF; see Figures 3 and 4 for Waveforms)

Symbol	Parameter	V _{CC} * (V)	MC74ACT00						Unit	
			T _A = +25°C			T _A = -40°C to +85°C		T _A = -55°C to +125°C		
			Min	Typ	Max	Min	Max	Min		Max
t _{PLH}	Propagation Delay	5.0	1.5	5.5	9.0	1.0	9.5	1.0	9.5	ns
t _{PHL}	Propagation Delay	5.0	1.5	4.0	7.0	1.0	8.0	1.0	8.0	ns

*Voltage Range 5.0 V is 5.0 V ± 0.5 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Test Conditions	Unit
C _{IN}	Input Capacitance	4.5	V _{CC} = 5.0 V	pF
C _{PD}	Power Dissipation Capacitance	30	V _{CC} = 5.0 V	pF

MC74AC00, MC74ACT00

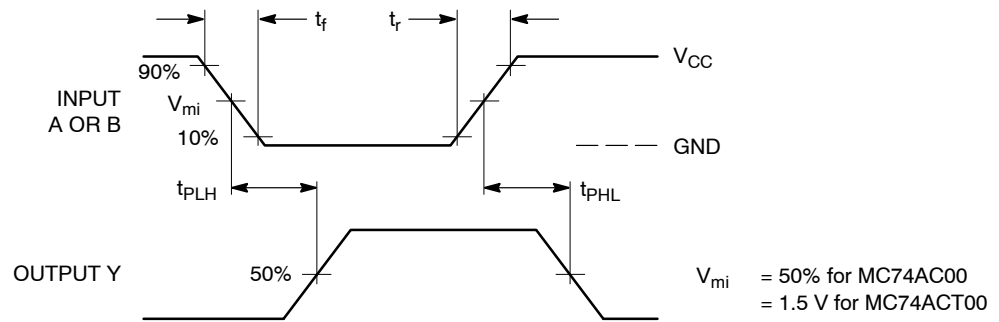
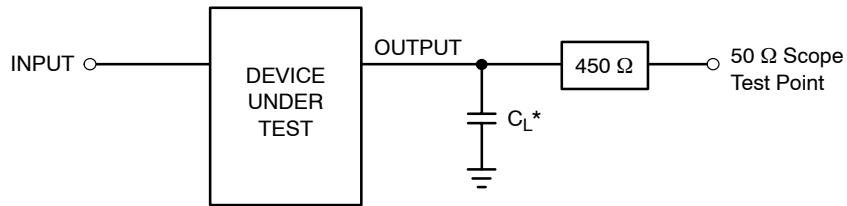


Figure 3. Switching Waveforms



*Includes all probe and jig capacitance

Figure 4. Test Circuit

ORDER INFORMATION

Device	Marking	Package	Shipping [†]
MC74AC00DG	AC00	SOIC-14 (Pb-Free)	55 Units / Rail
MC74AC00DR2G	AC00	SOIC-14 (Pb-Free)	2500 / Tape and Reel
MC74AC00DTR2G	AC 00	TSSOP-14 (Pb-Free)	
MC74ACT00DG	ACT00	SOIC-14 (Pb-Free)	55 Units / Rail
MC74ACT00DR2G	ACT00	SOIC-14 (Pb-Free)	2500 / Tape and Reel
MC74ACT00DTR2G	ACT 00	TSSOP-14 (Pb-Free)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

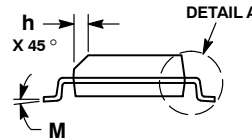
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 1:1

SOIC-14 NB
CASE 751A-03
ISSUE L

DATE 03 FEB 2016



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- Y = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-14 NB	PAGE 1 OF 2

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

SOIC-14
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. NO CONNECTION
 5. ANODE/CATHODE
 6. NO CONNECTION
 7. ANODE/CATHODE
 8. ANODE/CATHODE
 9. ANODE/CATHODE
 10. NO CONNECTION
 11. ANODE/CATHODE
 12. ANODE/CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 2:
 CANCELLED

STYLE 3:
 PIN 1. NO CONNECTION
 2. ANODE
 3. ANODE
 4. NO CONNECTION
 5. ANODE
 6. NO CONNECTION
 7. ANODE
 8. ANODE
 9. ANODE
 10. NO CONNECTION
 11. ANODE
 12. ANODE
 13. NO CONNECTION
 14. COMMON CATHODE

STYLE 4:
 PIN 1. NO CONNECTION
 2. CATHODE
 3. CATHODE
 4. NO CONNECTION
 5. CATHODE
 6. NO CONNECTION
 7. CATHODE
 8. CATHODE
 9. CATHODE
 10. NO CONNECTION
 11. CATHODE
 12. CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 5:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. ANODE/CATHODE
 5. ANODE/CATHODE
 6. NO CONNECTION
 7. COMMON ANODE
 8. COMMON CATHODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. ANODE/CATHODE
 12. ANODE/CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 6:
 PIN 1. CATHODE
 2. CATHODE
 3. CATHODE
 4. CATHODE
 5. CATHODE
 6. CATHODE
 7. CATHODE
 8. ANODE
 9. ANODE
 10. ANODE
 11. ANODE
 12. ANODE
 13. ANODE
 14. ANODE

STYLE 7:
 PIN 1. ANODE/CATHODE
 2. COMMON ANODE
 3. COMMON CATHODE
 4. ANODE/CATHODE
 5. ANODE/CATHODE
 6. ANODE/CATHODE
 7. ANODE/CATHODE
 8. ANODE/CATHODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. COMMON CATHODE
 12. COMMON ANODE
 13. ANODE/CATHODE
 14. ANODE/CATHODE

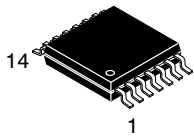
STYLE 8:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. NO CONNECTION
 5. ANODE/CATHODE
 6. ANODE/CATHODE
 7. COMMON ANODE
 8. COMMON ANODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. NO CONNECTION
 12. ANODE/CATHODE
 13. ANODE/CATHODE
 14. COMMON CATHODE

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-14 NB	PAGE 2 OF 2

onsemi and **ONSEMI** are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



TSSOP-14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016

SCALE 2:1



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

GENERIC MARKING DIAGRAM*

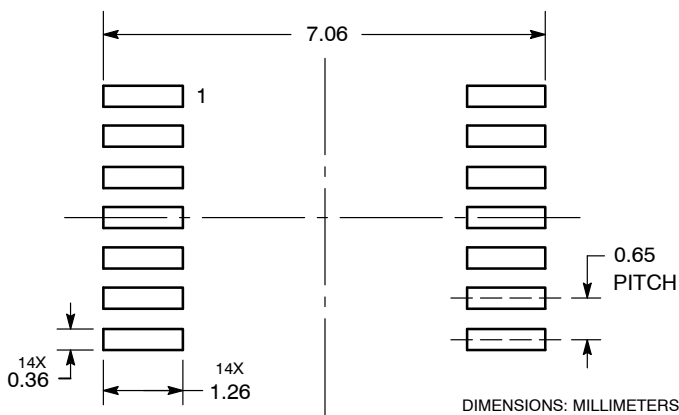


- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

SOLDERING FOOTPRINT



DOCUMENT NUMBER:	98ASH70246A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSSOP-14 WB	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View MC74AC00DR2](#) on WIN SOURCE

 [ON Semiconductor](#) Information

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management